TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7S32F, TC7S32FU

2-INPUT OR GATE

The TC7S32 is a high speed C²MOS 2-INPUT OR GATE fabricated with silicon gate C²MOS technology. It achieves high speed operation similar to equivalent LSTTL while maintaining the C²MOS low power dissipation.

The internal circuit is composed of 2 stages including buffer output, which enables high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Output currents are 1/2 compared to TC74HC series

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FEATURES

•	High Speed	$t_{pd} = 7ns \text{ (Typ.)}$
		at $V_{CC} = 5V$

Low Power Dissipation ICC = 1μ A (Max.)

at Ta = 25°C

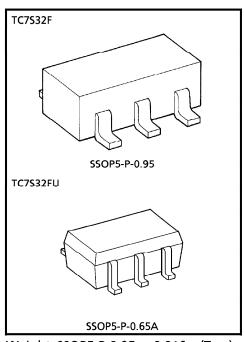
High Noise Immunity V_{NIH} = V_{NIL} = 28% V_{CC} (Min.)

Output Drive Capability 5 LSTTL Loads

Symmetrical Output Impedance ... $|I_{OH}| = I_{OL}$ = 2mA (Min.)

Balanced Propagation Delays t_{pLH}≒t_{pHL}

Wide Operating Voltage Range ... VCC (opr) = 2~6V

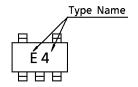


Weight SSOP5-P-0.95 : 0.016g (Typ.) SSOP5-P-0.65A : 0.006g (Typ.)

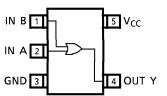
MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V _C C	-0.5~7	V
DC Input Voltage	V _{IN}	-0.5~V _{CC} +0.5	V
DC Output Voltage	V _{OUT}	-0.5~V _{CC} +0.5	V
Input Diode Current	ΙΚ	± 20	mA
Output Diode Current	^I ок	± 20	mA
DC Output Current	lout	± 12.5	mΑ
DC V _{CC} /Ground Current	Icc	± 25	mΑ
Power Dissipation	P _D	200	mW
Storage Temperature	T _{stg}	- 65∼150	°C
Lead Temperature (10s)	TL	260	°C

MARKING



PIN ASSIGNMENT (TOP VIEW)



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LOGIC DIAGRAM

IN B
$$(1)$$
 $\geqslant 1$ (4) OUT Y

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	2~6	V
Input Voltage	VIN	0~V _{CC}	V
Output Voltage	Vout	0~V _{CC}	V
Operating Temperature	T _{opr}	- 40~85	°C
		$0\sim1000 \ (V_{CC}=2.0V)$	
Input Rise and Fall Time	t _r , t _f	$0 \sim 500 \ (V_{CC} = 4.5V)$	ns
		$0 \sim 400 \ (V_{CC} = 6.0V)$	

DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	DL TEST CONDITION			Ta = 25°C			Ta = -4	UNIT	
CHARACTERISTIC	3 TIVIDOL			Vcc	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High-Level				2.0	1.5	_	_	1.5	_	
Input Voltage	VIH		_	4.5	3.15	—	—	3.15	—	V
input voltage				6.0	4.2	_	_	4.2	_	
Low-Level				2.0	—	—	0.5	—	0.5	
Input Voltage	VIL		_	4.5	—	—	1.35	—	1.35	V
input voitage				6.0	_		1.8		1.8	
				2.0	1.9	2.0	<u> </u>	1.9	_	V
High Lavel	V _{ОН}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -20\mu A$	4.5	4.4	4.5	—	4.4	—	
High-Level				6.0	5.9	6.0	_	5.9	_	
Output Voltage			I _{OH} = -2mA	4.5	4.18	4.31	—	4.13	_	
			$I_{OH} = -2.6 \text{mA}$	6.0	5.68	5.80	_	5.63	_	
	V _{OL}	V _{IN} = V _{IL}		2.0	_	0.0	0.1	_	0.1	
Low-Level			$I_{OL} = 20 \mu A$	4.5	—	0.0	0.1	_	0.1	
				6.0	_	0.0	0.1	_	0.1	V
Output Voltage			I _{OL} = 2mA	4.5	_	0.17	0.26	_	0.33	
			$I_{OL} = 2.6 mA$	6.0	_	0.18	0.26	_	0.33	
Input Leakage Current	lIN	V _{IN} = V _{CC} or GND		6.0	_	_	± 0.1		± 1.0	μ A
Quiescent Supply Current	lcc	V _{IN} = V _{CC} or GND		6.0	_	_	1.0	_	10.0	μΑ

Output currents are 1/2 compared to TC74HC series models.

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 The information contained herein is subject to change without notice.

AC ELECTRICAL CHARACTERISTICS ($C_L = 15pF$, Input $t_r = t_f = 6ns$, $V_{CC} = 15pF$
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CHARACTERISTIC	SYMBOL	TEST CONDITION	Т	UNIT		
CHARACTERISTIC	STIVIBOL TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Output Transition	tTLH			_	10	20
Time	tTHL	_		3	10	ns
Propagation Delay	t _{pLH}			7	15	20
Time	t _{pHL}	_	_		13	ns

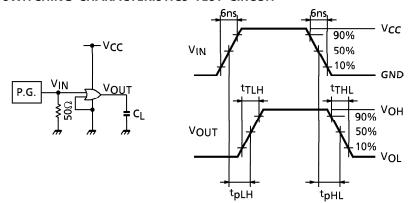
AC ELECTRICAL CHARACTERISTICS ($C_L = 50pF$, Input $t_r = t_f = 6ns$)

CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -4	UNIT	
CHARACTERISTIC	JIIVIDOL		Vcc	MIN.	TYP.	MAX.	MIN.	MAX.	OIVII
Output Transition	+		2.0	_	50	125	_	155	
Time	t _{TLH}	_	4.5	 —	14	25	_	31	ns
Time	[†] THL		6.0	—	12	21	—	26	
Propagation Dalay	_		2.0	_	48	100	_	125	
Propagation Delay	t _{pLH}	_	4.5	l —	12	20	—	25	ns
Time	t _{pHL}		6.0	_	9	17	—	21	
Input Capacitance	CIN	_		_	5	10	_	10	
Power Dissipation C _{PD}		(Note 1)		_	10	_	_	_	pF

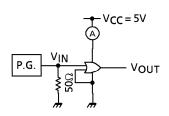
Note 1: CpD defined as the value of internal equivalent capacitance of IC which is calculated from the operating current consumption without load (refer to Test Circuit).

Average operating current can be obtained by the equation hereunder.

SWITCHING CHARACTERISTICS TEST CIRCUIT



ICC (opr) TEST CIRCUIT

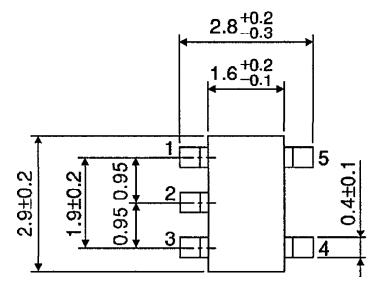


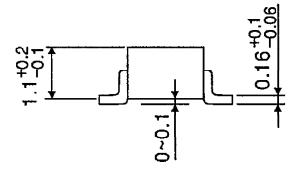
Input waveform is the same as that in case of switching characteristics test.

OUTLINE DRAWING

SSOP5-P-0.95





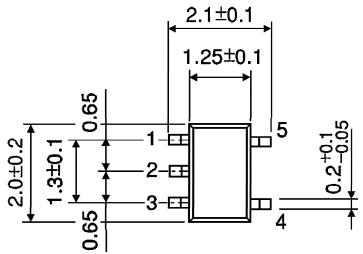


Weight: 0.016g (Typ.)

Unit: mm

OUTLINE DRAWING

SSOP5-P-0.65A



0.940.1

Weight: 0.006g (Typ.)